NSN 5961-00-124-9955

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-124-9955 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Internal Configuration:** Field effect **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 25.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 30.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5349 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No